2SC4154

FOR LOW FREQUENCY AMPLIFY APPLICATION SILICON NPN EPITAXIAL TYPE (Super mini type)

DESCRIPTION

2SC4154 is a super mini package resin sealed silicon NPN epitaxial transistor,

It is designed for low frequency voltage application.

Complementary with ISA1602AM1.

FEATURE

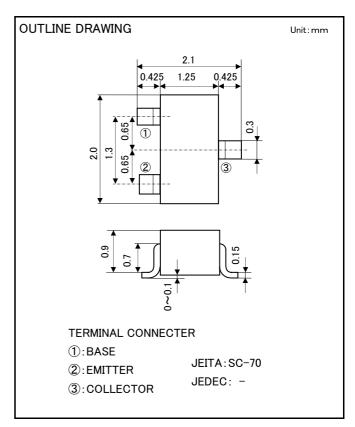
- Small collector to emitter saturation voltage.
 - $VCE(sat) = 0.3V \ max(@Ic = 100mA, IB = 10mA)$
- Excellent linearity of DC forward gain.
- Super mini package for easy mounting

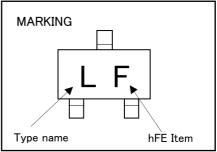
APPLICATION

For Hybrid IC, small type machine low frequency voltage Amplify application.

MAXIMUM RATINGS(Ta=25°C)

Symbol	Parameter	Ratings	Unit
V _{CBO}	Collector to Base voltage	50	٧
V_{CEO}	Collector to Emitter voltage	50	٧
V _{EBO}	Emitter to Base voltage	6	٧
I o	Collector current	200	mA
P _c	Collector dissipation	200	mW
T _j	Junction temperature	+150	°C
T_{stg}	Storage temperature	-55 ~ +150	လူ





ELECTRICAL CHARACTERISTICS (Ta=25°C)

	Symbol	T	Limits			11.2
Parameter		Test conditions	Min	Тур	Max	Unit
C to E breakdown voltage	V(BR)ceo	I _C =100 μ A ,R _{BE} =∞	50	-	-	٧
Collector cut off current	ICBO	V_{CB} =50V, I_{E} =0mA	-	-	0.1	μΑ
Emitter cut off current	IEBO	V_{EB} =6V, I $_{C}$ =0mA	-	-	0.1	μΑ
DC forward current gain※	hFE	V_{CE} =6V, I_{C} =1mA	150	ı	500	-
DC forward current gain	hFE	V_{CE} =6V, I $_{C}$ =0.1mA	90	-	-	-
C to E Saturation Voltage	VCE(sat)	I _C =100mA ,I _B =10mA	-	-	0.3	٧
Gain bandwidth product	fT	V _{CE} =6V, I _E =-10mA	-	200	-	MHz
Collector output capacitance	Cob	V _{CB} =6V, I _E =0,f=1MHz	ı	2.5	-	pF
Noise figure	NF	V_{CE} =6 V , I_{E} =-0.1 m A,f=1 k Hz,RG=2 k Ω	_	-	15	dB

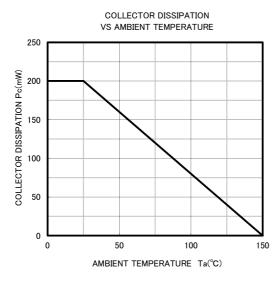
※) It shows hFE classification at right table.

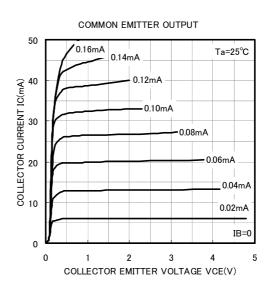
Item	Е	F
hFE Item	150~300	250~500

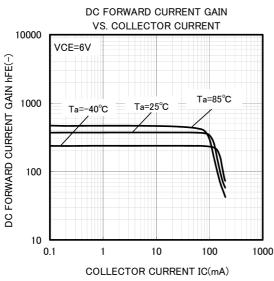
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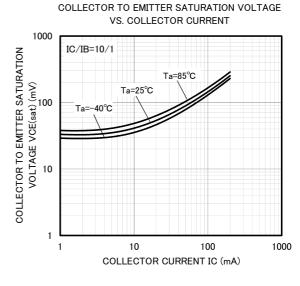
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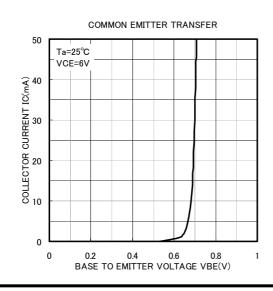
TYPICAL CHARACTERISTICS

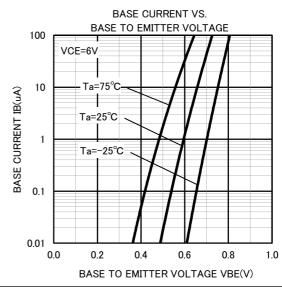






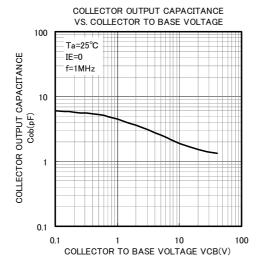


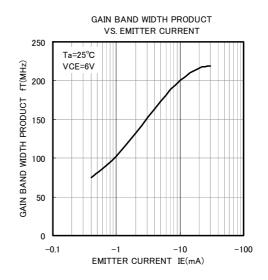


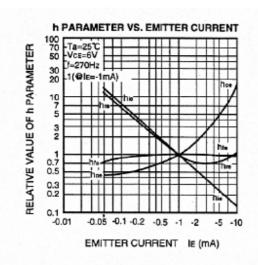


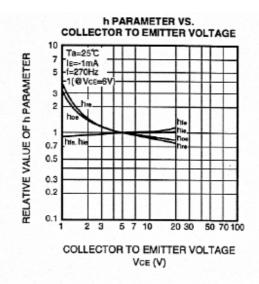
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COMMON EMITTER h PARAMETER (TYPICAL VALUE)

Symbol	Parameter	Test conditions	Limits	Unit
hie	Closed loop small signal input impedance	Ta=25°C	8.5	kΩ
hre	Open loop small signal reverse voltage amplification factor Closed loop small signal forward current amplification factor IE=-1mA		0.1	×10-3
hte			300	
hoe	Open loop small signal output admittance	1=270Hz	5.5	μS



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